



Form PTO 1449
(Modified)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

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SERIAL NO.
10/615,181

LIST OF REFERENCES CITED BY APPLICANT

APPLICANT
Daisaburo TAKASHIMA

FILING DATE
July 9, 2003

GROUP

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION	
					YES	NO
	AQ					
	AP					
	AQ					
	AR					
	AS					
	AT					
	AU					
	AV					

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)

GA	AW	D. TAKASHIMA, et al., IEEE Journal of Solid-State Circuits, vol. 33, no. 5, pages 787-792, "HIGH-DENSITY CHAIN FERROELECTRIC RANDOM ACCESS MEMORY (CHAIN FRAM)", May 1998
GA	AX	S. ONISHI, et al., IEDM, pages 843-846, "A HALF-MICRON FERROELECTRIC MEMORY CELL TECHNOLOGY WITH STACKED CAPACITOR STRUCTURE", 1994
	AY	
	AZ	

☐ Additional References sheet(s) attached

Examiner

GA

Date Considered

9-25-04

*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.